

# **RP131x SERIES**

# LOW ON RESISTANCE / LOW VOLTAGE 1A LDO

NO.EA-174-200128

# **OUTLINE**

The RP131x Series are voltage-regulators with a built-in low ON-resistance transistor and output current is 1A capability. These ICs are capable of the low input voltage (Min.1.6V) and also the minimum output voltage can be set from 0.8V. (The output voltage is fixed in the IC.)

Each of these ICs consists of a voltage reference unit, an error amplifier, a resistor net for setting output voltage, a chip enable circuit, current limit circuits for over-current and short, and a thermal-shutdown circuit.

A standby mode with ultra low supply current can be realized with the chip enable function.

The packages for these ICs are DFN1616-6B and DFN(PLP)1820-6 which are suitable for high density mounting of the ICs on boards. SOT-89-5, HSOP-6J and TO-252-5-P2 with high power dissipation are also available.

# **FEATURES**

Output Current	Min. 1A
Supply Current	
Standby Current	
Input Voltage Range	
Output Voltage Range	
Dropout Voltage	
Ripple Rejection	Typ. 70dB (f=1kHz, Vo∪т=2.8V)
Output Voltage Accuracy	±1.0%
• Temperature-Drift Coefficient of Output Voltage	Typ. ±100ppm/°C
Line Regulation	Typ. 0.05%/V
Load Regulation	Тур. 20mV at louт=300mA, Тур. 80mV at louт=1A
Packages	DFN1616-6B, DFN(PLP)1820-6, SOT-89-5, HSOP-6J,
	TO-252-5-P2
Built-in Inrush current limit circuit	Typ. 500mA
Built-in Fold-Back Protection Circuit	Typ. 250mA (Current at short mode)
Built-in Thermal Shutdown Circuit	Thermal Shutdown Temperature ; Typ. 165°C
	Released Temperature; Typ. 135°C
Built-in Auto Discharge Function	D version
• Ceramic capacitors are recommended to be used v	vith this IC 2.2μF or more (Vouτ≤3.6V)
	$4.7\mu F$ or more (Vout>3.6V)

# **APPLICATIONS**

- Power source for battery-powered equipment.
- Power source for portable communication equipment.
- Power source for electrical appliances such as cameras, VCRs and camcorders.
- Power source for Notebook PC.
- Power source for home appliances.

(1) For other voltages, please refer to MARK INFORMATIONS.

NO.EA-174-200128

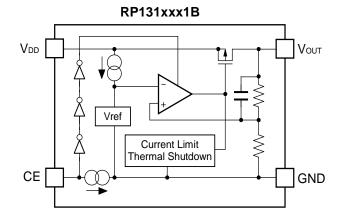
# **SELECTION GUIDE**

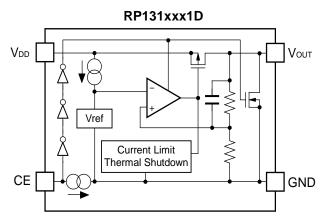
The output voltage, auto discharge function, package for the ICs can be selected at the user's request.

Product Name	Package	Quantity per Reel	Pb Free	Halogen Free
RP131Lxx1*-TR	DFN1616-6B	5,000 pcs	Yes	Yes
RP131Kxx1*-TR	DFN(PLP)1820-6	5,000 pcs	Yes	Yes
RP131Hxx1*-T1-FE	SOT-89-5	1,000 pcs	Yes	Yes
RP131Sxx1*-E2-FE	HSOP-6J	1,000 pcs	Yes	Yes
RP131Jxx1*-T1-FE	TO-252-5-P2	3,000 pcs	Yes	Yes

- xx : The output voltage can be designated in the range from 0.8V(08) to 5.5V(55) in 0.1V steps. (For other voltages, please refer to MARK INFORMATIONS.)
  - \*: The auto discharge function at off state are options as follows.(1)
    - (B) without auto discharge function at off state
    - (D) with auto discharge function at off state

# **BLOCK DIAGRAMS**

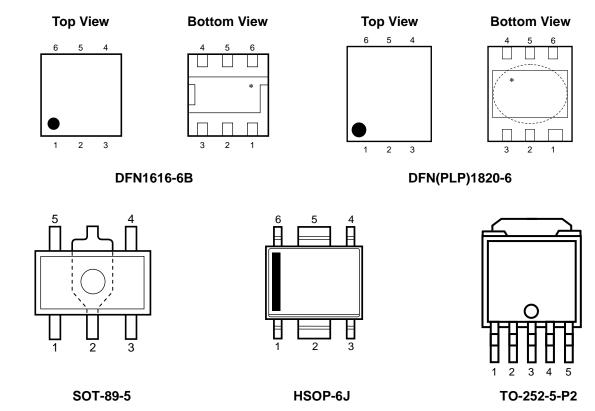




<sup>(1)</sup> Auto-discharge function quickly lowers the output voltage to 0V, when the chip enable signal is switched from the active mode to the standby mode, by releasing the electrical charge accumulated in the external capacitor.

NO.EA-174-200128

# **PIN DESCRIPTIONS**



<sup>\*</sup>Tab is GND level. (They are connected to the reverse side of this IC.) The tab is better to be connected to the GND, but leaving it open is also acceptable.

# RP131L (DFN1616-6B) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin <sup>(1)</sup>
2	VOUt	Output Pin <sup>(1)</sup>
3	GND	Ground Pin
4	CE	Chip Enable Pin ("H" Active)
5	VDD	Input Pin <sup>(1)</sup>
6	VDD	Input Pin <sup>(1)</sup>

<sup>(1)</sup> When you use this IC, please make sure be wired with 1pin with 2pin and 5pin with 6pin.

NO.EA-174-200128

# RP131K (DFN(PLP)1820-6) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin <sup>(1)</sup>
2	VOUT	Output Pin <sup>(1)</sup>
3	GND	Ground Pin
4	CE	Chip Enable Pin ("H" Active)
5	VDD	Input Pin <sup>(1)</sup>
6	VDD	Input Pin <sup>(1)</sup>

# RP131H (SOT-89-5) Pin Description

Pin No.	Symbol	Pin Description
1	NC	No Connection
2	GND	Ground Pin
3	CE	Chip Enable Pin ("H" Active)
4	VDD	Input Pin
5	VOUT	Output Pin

# RP131S (HSOP-6J) Pin Description

Pin No.	Symbol	Pin Description
1	VOUT	Output Pin
2	GND	Ground Pin <sup>(2)</sup>
3	NC	No Connection
4	CE	Chip Enable Pin ("H" Active)
5	GND	Ground Pin <sup>(2)</sup>
6	VDD	Input Pin

# RP131J (TO-252-5-P2) Pin Description

Pin No.	Symbol	Pin Description
1	Vouт	Output Pin
2	GND	Ground Pin <sup>(3)</sup>
3	GND	Ground Pin <sup>(3)</sup>
4	CE	Chip Enable Pin ("H" Active)
5	V <sub>DD</sub>	Input Pin

<sup>(1)</sup> When you use this IC, please make sure be wired with 1pin with 2pin and 5pin with 6pin.

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<sup>(2)</sup> When you use this IC, please make sure be wired with 2pin and 5pin.

<sup>(3)</sup> When you use this IC, please make sure be wired with 2pin and 3pin.

NO.EA-174-200128

# ABSOLUTE MAXIMUM RATINGS

Symbol		Item					
Vin	Input Voltage	Input Voltage					
Vce	Input Voltage (CE Pin)	)	-0.3 to 7.0	V			
Vouт	Output Voltage	Output Voltage					
		DFN1616-6B, JEDEC STD.51-7	2400				
	Power Dissipation <sup>(1)</sup>	DFN(PLP)1820-6, JEDEC STD.51-7	2200	mW			
Po		SOT-89-5, JEDEC STD.51-7	2600				
		HSOP-6J, JEDEC STD.51-7	2700				
		TO-252-5-P2, JEDEC STD.51-7	3800				
Tj	Junction Temperature	-40 to 125	°C				
Tstg	Storage Temperature	Range	-55 to 125	°C			

# **ABSOLUTE MAXIMUM RATINGS**

Electronic and mechanical stress momentarily exceeded absolute maximum ratings may cause the permanent damages and may degrade the life time and safety for both device and system using the device in the field.

The functional operation at or over these absolute maximum ratings is not assured.

# RECOMMENDED OPERATING CONDITIONS

Symbol	Item	Rating	Unit
V <sub>IN</sub>	Input Voltage	1.6 to 6.5	V
Ta	Operating Temperature Range	-40 to 85	°C

#### RECOMMENDED OPERATING CONDITIONS

All of electronic equipment should be designed that the mounted semiconductor devices operate within the recommended operating conditions. The semiconductor devices cannot operate normally over the recommended operating conditions, even if when they are used over such ratings by momentary electronic noise or surge. And the semiconductor devices may receive serious damage when they continue to operate over the recommended operating conditions.

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<sup>(1)</sup> Refer to POWER DISSIPATION for detailed information.

R	<b>P</b> 1	3	1	Y
П	ГІ	J		А

NO.EA-174-200128

# **ELECTRICAL CHARACTERISTICS**

VIN=	Set Vour+1V,	Іоит=	1mA										
The	specification	in		is	checked	and	guaranteed	by	design	engineering	at	-40°C≤Ta≤85°C,	unless
othe	rwise noted.												

**RP131xxx1B/D** (Ta = 25°C)

Symbol	Item	Conditions			Тур.	Max.	Unit	
		T- 25°C	Vоит>1.5V	×0.99		×1.01	V	
\	Outrout Valtage	Ta = 25°C	Vouτ≤1.5V	-15		15	mV	
Vоит	Output Voltage	–40°C ≤ Ta t≤ 85°C	Vоит>1.5V	×0.974		×1.018	V	
		-40°C ≤ 1a t≤ 65°C	Vо∪т≤1.5V	-40		27	mV	
$\Delta V$ out/	Load Dogulation	0.1mA ≤ Iouт ≤ 300mA	\		20	40	mV	
$\Delta {\sf I}$ оυт	Load Regulation	0.1mA ≤ I <sub>ОUT</sub> ≤ 1A					IIIV	
VDIF	Dropout Voltage		Refer to the follow	wing table	)			
Iss	Supply Current	IOUT=0mA (VIN=6.5V)	)		65	90	μА	
Istandby	Standby Current	VCE=0V, VIN=6.5V			0.15	0.60	μА	
$\Delta V_{ ext{OUT}}/$	Line Regulation	Set Vour+0.5V ≤ V <sub>IN</sub> ≤ *However, V <sub>IN</sub> ≥ 1.6V		0.05	0.1	%/V		
RR	Dinalo Deigotian	f=1kHz	Vо∪т≤3.3V		70		٩D	
KK	Ripple Rejection	Ripple 0.2Vp-p lout=100mA	Vout>3.3V		60		- dB	
Vin	Input Voltage			1.6		6.5	V	
Інм	Output Current Limit			1			Α	
ΔVουτ/ ΔTa	Output Voltage Temperature Coefficient	–40°C≤Ta≤85°C			±100		ppm /°C	
Isc	Short Current Limit	Vout=0V			250		mA	
<b>I</b> PD	CE Pull-down Current				0.3		μА	
Vceh	CE Input Voltage "H"			1.0			V	
VCEL	CE Input Voltage "L"					0.4	V	
en	Output Noise	BW=10Hz to 100kHz,		45		μVrms		
T <sub>TSD</sub>	Thermal Shutdown Temperature	Junction Temperature		165		°C		
TTSR	Thermal Shutdown Released Temperature	Junction Temperature	)		135		°C	
RLOW	Low Output Nch Tr. ON Resistance (of D version)	VIN=4.0V, VCE=0V			30		Ω	

All test items listed under Electrical Characteristics are done under the pulse load condition (Tj≈Ta = 25°C) except for Output Noise, Ripple Rejection, Output Voltage Temperature Coefficient, Dropout Voltage at 1A Output Current and Thermal Shutdown items.

RP131x	
NO.EA-174-200128	

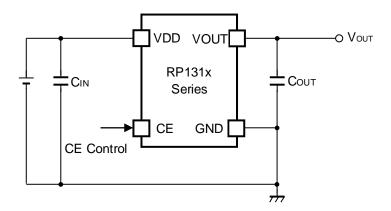
The specification in  $\square$  is checked and guaranteed by design engineering at  $-40^{\circ}\text{C} \leq \text{Ta} \leq 85^{\circ}\text{C}$ , unless otherwise noted.

Dropout Voltage						(Ta = 25°C)
Output Voltage			<b>Dropout Vol</b>	tage VDIF (V)		
<b>V</b> оит <b>(V)</b>	Condition	Тур.	Max.	Condition	Тур.	Max.
0.8 ≤ Vout < 0.9		0.600	0.780		1.100	1.650
0.9 ≤ Vout < 1.0		0.550	0.690		1.050	1.500
1.0 ≤ Vouт < 1.1		0.450	0.610		1.000	1.450
1.1 ≤ Vouт < 1.2		0.340	0.540		0.930	1.420
1.2 ≤ Vouт < 1.5	— Iоит=300mA	0.290	0.500	Тоит=1А	0.900	1.380
1.5 ≤ Vouт < 2.6		0.230	0.310		0.700	1.100
2.6 ≤ Vout < 3.3		0.150	0.180		0.500	0.750
3.3 ≤ Vout ≤ 5.5		0.140	0.170	1	0.450	0.650

NO.EA-174-200128

### APPLICATION INFORMATION

### **Typical Application Circuits**



Recommendation value of the external capacitors

Vouт		Capacitors	
V< 2.6V	CIN	Kyocera 2.2µF (size:1005)	[CM05X5R225M06AB]
V <sub>OUT</sub> ≤ 3.6V	Соит	Kyocera 2.2μF (size:1608)	[CM105X5R225K06AB]
\/> 2.6\/	CIN	Kyocera 2.2μF (size:1608)	[CM105X5R225K06AB]
$V_{OUT} > 3.6V$	Соит	Kyocera 4.7µF (size:1608)	[CM105X5R475M06AB]

#### **Technical Notes on the External Components**

When using this IC, consider following points:

### **Phase Compensation**

In these ICs, phase compensation is made for securing stable operation even if the load current is varied. For this purpose, use a capacitor C<sub>OUT</sub> with good frequency characteristics and ESR (Equivalent Series Resistance).

If a tantalum capacitor is used, and its ESR of  $C_{OUT}$  is large, the loop oscillation may result. Because of this, select  $C_{OUT}$  carefully considering its frequency characteristics.

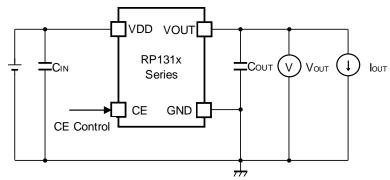
### **PCB** Layout

Make  $V_{DD}$  and GND lines sufficient. If their impedance is high, noise pickup or unstable operation may result. Connect a capacitor  $C_{IN}$  between  $V_{DD}$  and GND pin with a capacitance value as "Recommendation value of the external capacitors" above or more, and as close as possible to the pins.

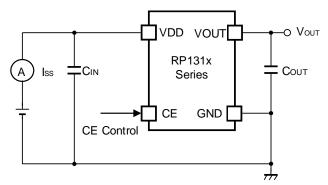
Set external components, especially the output capacitor  $C_{\text{OUT}}$ , as close as possible to the ICs, and make wiring as short as possible.

NO.EA-174-200128

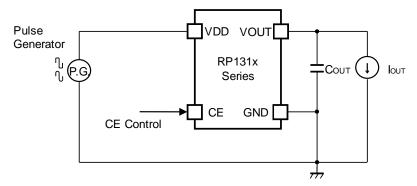
### **TEST CIRCUITS**



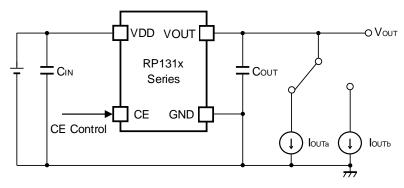
**Basic Test Circuit** 



**Test Circuit for Supply Current** 



**Test Circuit for Ripple Rejection** 



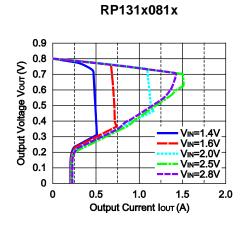
**Test Circuit for Load Transient Response** 

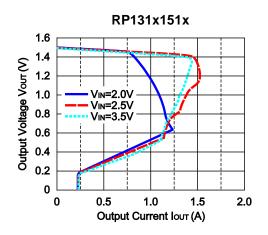
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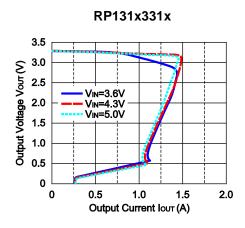
# TYPICAL CHARACTERISTICS

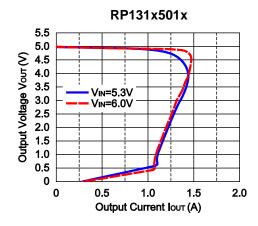
Typical Characteristics are intended to be used as reference data; they are not guaranteed.

### 1) Output Voltage vs. Output Current (Ta = 25°C)

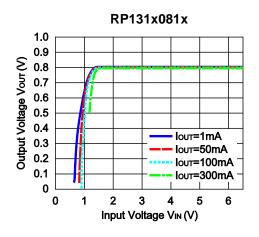


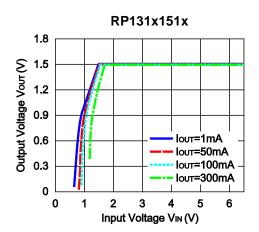




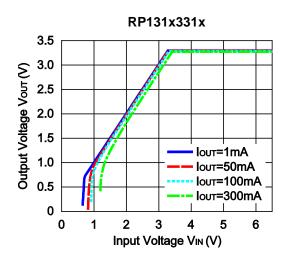


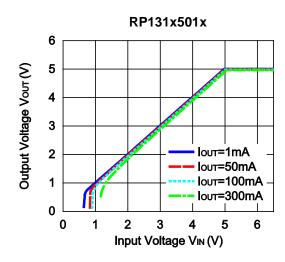
# 2) Output Voltage vs. Input Voltage (Ta=25°C)



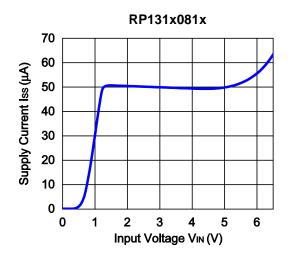


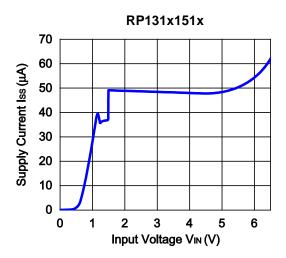
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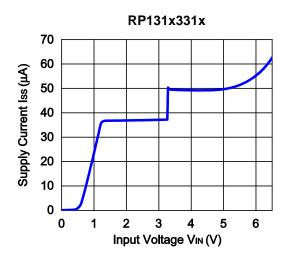


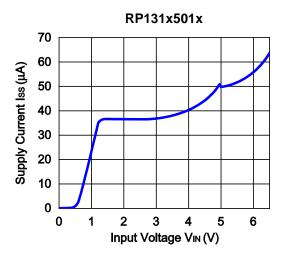


# 3) Supply Current vs. Input Voltage (Ta=25°C)



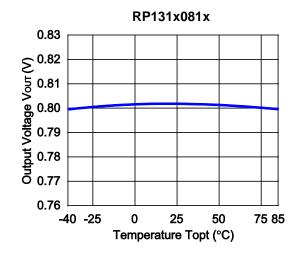


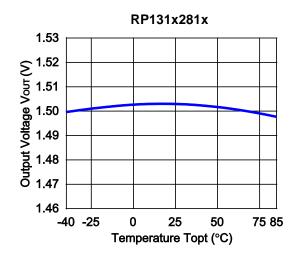


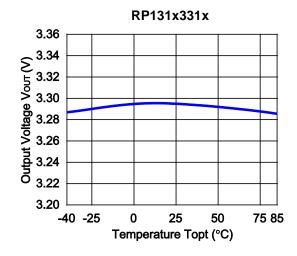


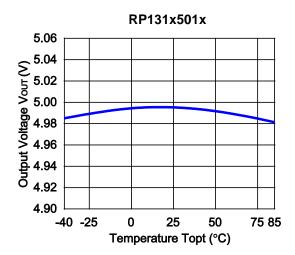
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# 4) Output Voltage vs. Temperature

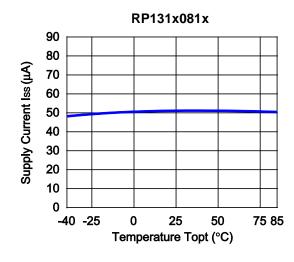


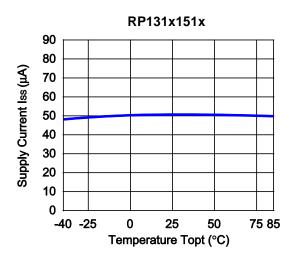




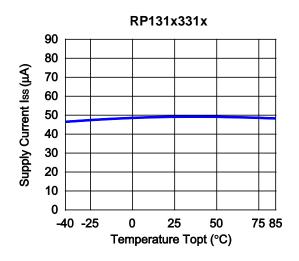


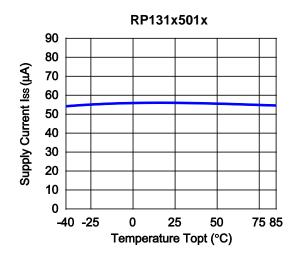
# 5) Supply Current vs. Temperature



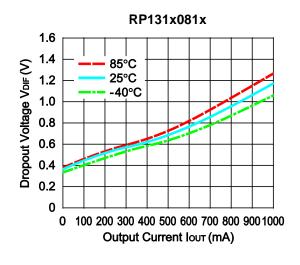


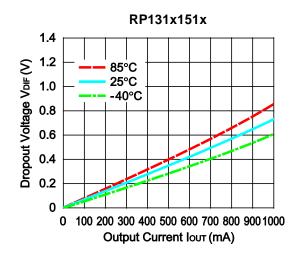
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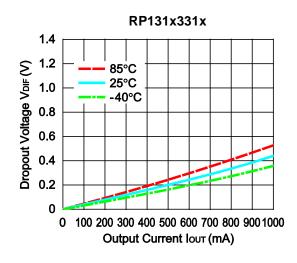


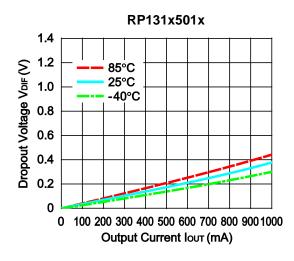


# 6) Dropout Voltage vs. Output Current



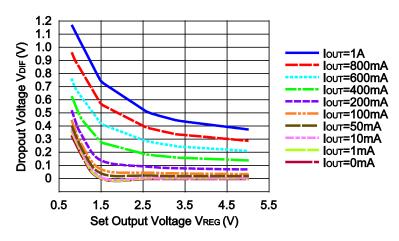




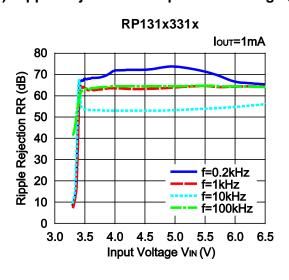


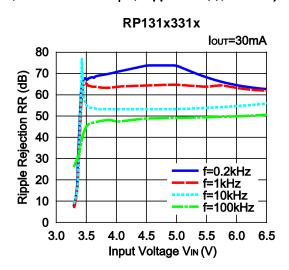
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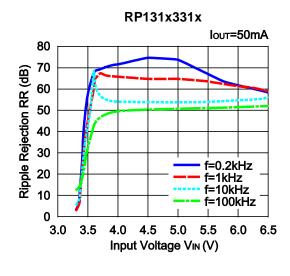
# 7) Dropout Voltage vs. Set Output Voltage

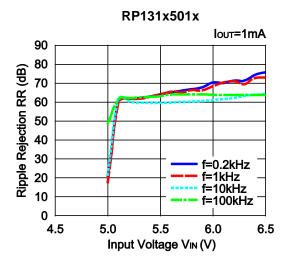


### 8) Ripple Rejection vs. Input Bias Voltage (C1=none, C2=Ceramic 1.0μF, Ripple=0.2V<sub>PP</sub>, Ta=25°C)

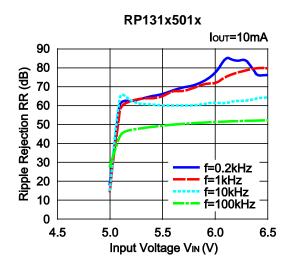


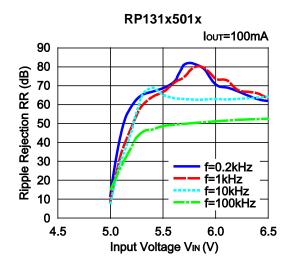




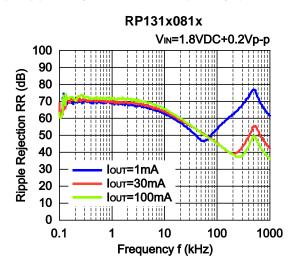


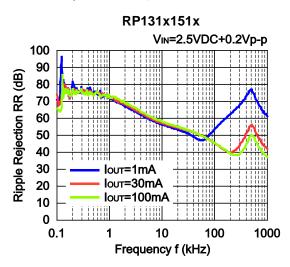
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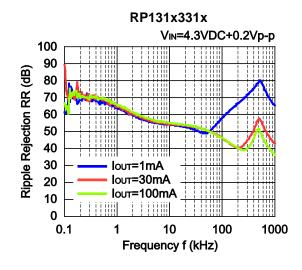


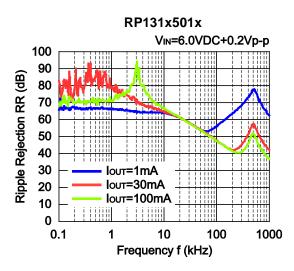


# 9) Ripple Rejection vs. Frequency (C1=none, C2=Ceramic 4.7μF, Ta=25°C)









3

6

5

Input Voltage Vin (V)

Input Voltage Vin (V)

### **RP131x**

NO.EA-174-200128

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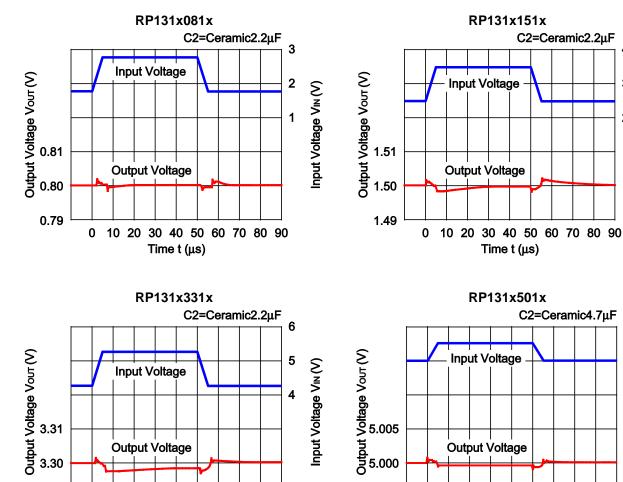
3.29

0

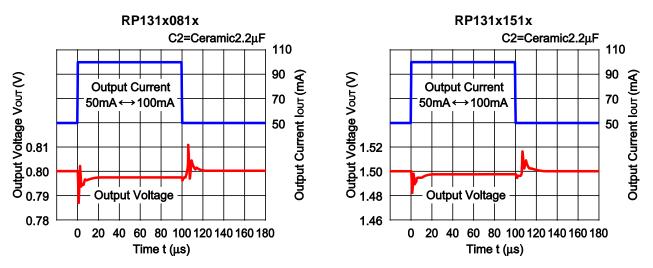
10 20 30 40 50 60 70 80 90

Time t (µs)

# 10) Input Transient Response (Ιουτ=100mA, tr=tf=5μs, C1=none, Ta=25°C)



# 11) Load Transient Response (tr=tf=0.5μs, C1=Ceramic 2.2μF, V<sub>IN</sub>=V<sub>OUT</sub>+1.0V, Topt=25°C)



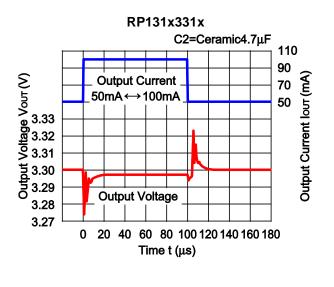
4.995

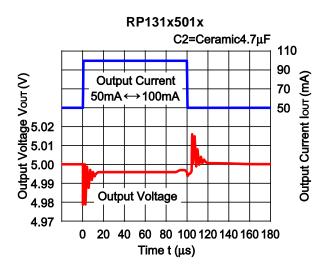
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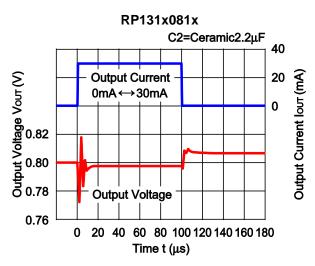
10 20 30 40 50 60 70 80 90

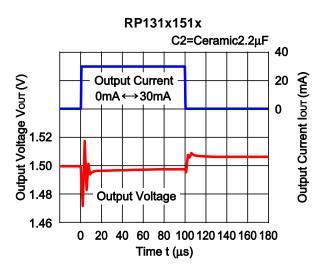
Time t (µs)

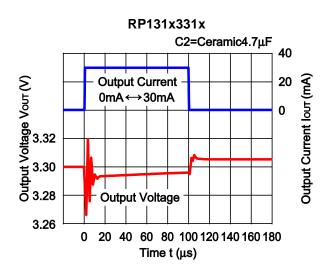
NO.EA-174-200128

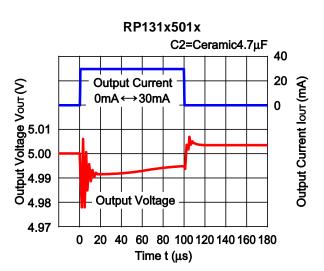




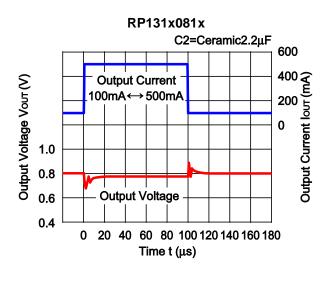


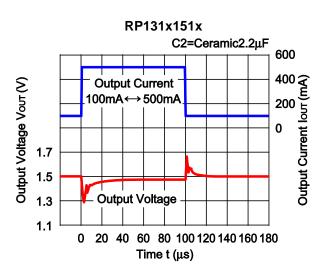


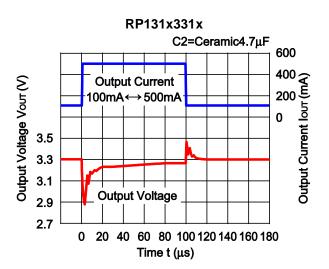


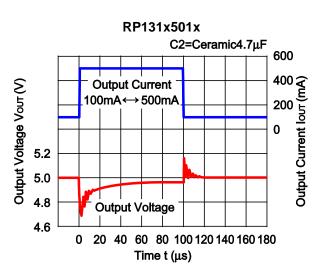


NO.EA-174-200128

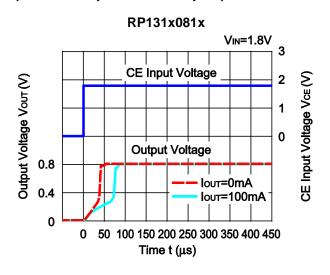


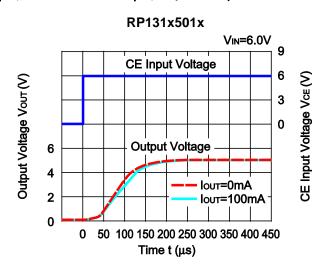






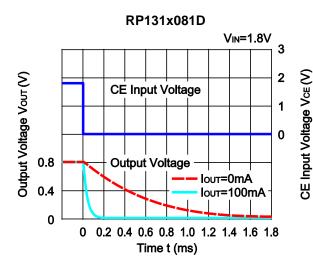
# 12) Turn On Speed with CE pin (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Topt=25°C)

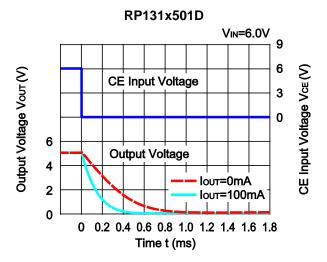




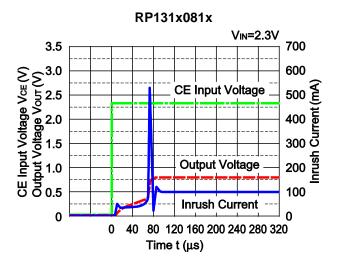
NO.EA-174-200128

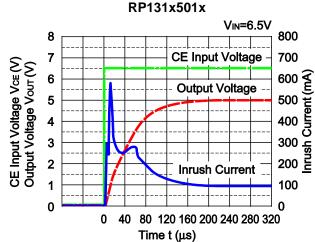
# 13) Turn Off Speed with CE pin (D Version) (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Ta=25°C)



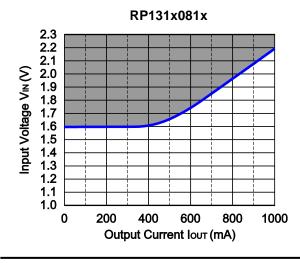


### 14) Inrush Current at turning on (C1=Ceramic 2.2μF, C2=Ceramic 4.7μF, Topt=25°C)





# 15) Minimum Operating Voltage



Hatched area is available for 0.8V output.

NO.EA-174-200128

# **ESR vs. Output Current**

When using these ICs, consider the following points:

The relations between Iout (Output Current) and ESR of an output capacitor are shown below.

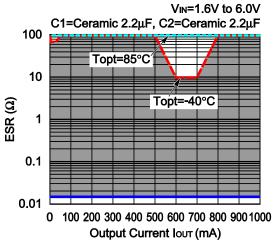
The conditions when the white noise level is under 40µV (Avg.) are marked as the hatched area in the graph.

#### Measurement conditions

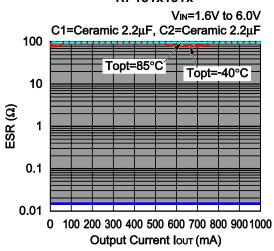
Frequency Band: 10Hz to 3MHz Temperature : -40°C to 85°C

C1 : 2.2μF (Kyocera, CM05X5R225M04AD)
C2 : 2.2μF (Kyocera, CM105X5R225K06AE)
4.7μF (Kyocera, CM105X5R475M06AB)

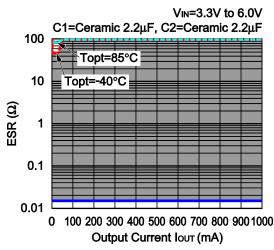
# RP131x081x



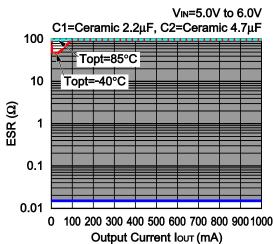
#### RP131x151x



#### RP131x331x



#### RP131x501x



# **POWER DISSIPATION**

# **DFN1616-6B**

Ver. A

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 15 pcs

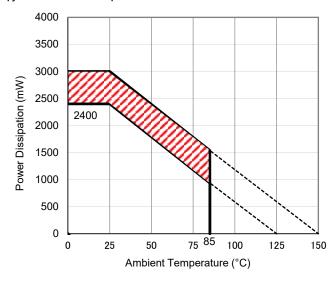
#### **Measurement Result**

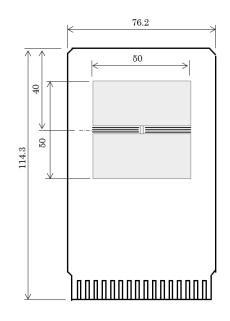
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	2400 mW
Thermal Resistance (θja)	θja = 41°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 11°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





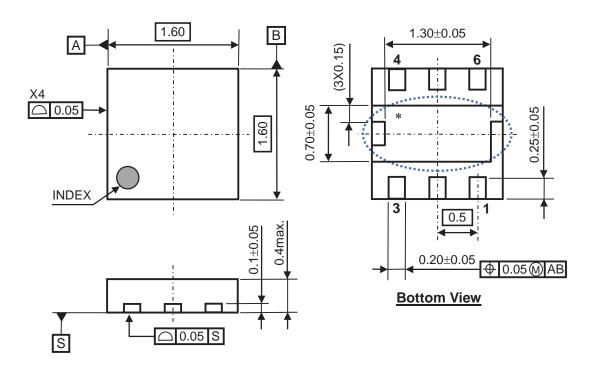
#### Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

i



# DFN1616-6B Package Dimensions (Unit: mm)

i

<sup>\*</sup> The tab on the bottom of the package shown by blue circle is a substrate potential (GND). It is recommended that this tab be connected to the ground plane pin on the board but it is possible to leave the tab floating.

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm
	Outer Layer (First Layer): Less than 95% of 50 mm Square
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.2 mm × 34 pcs

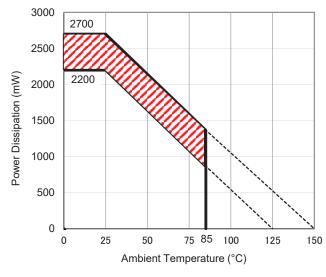
#### **Measurement Result**

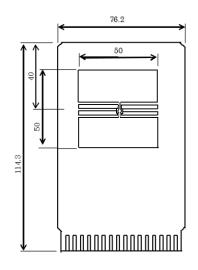
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	2200 mW
Thermal Resistance (θja)	θja = 45°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 18°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





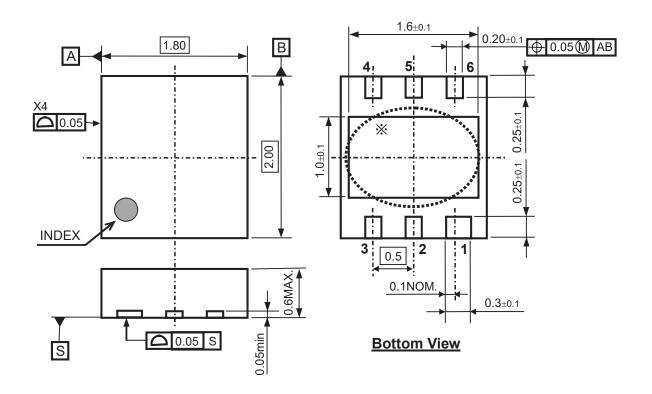
Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

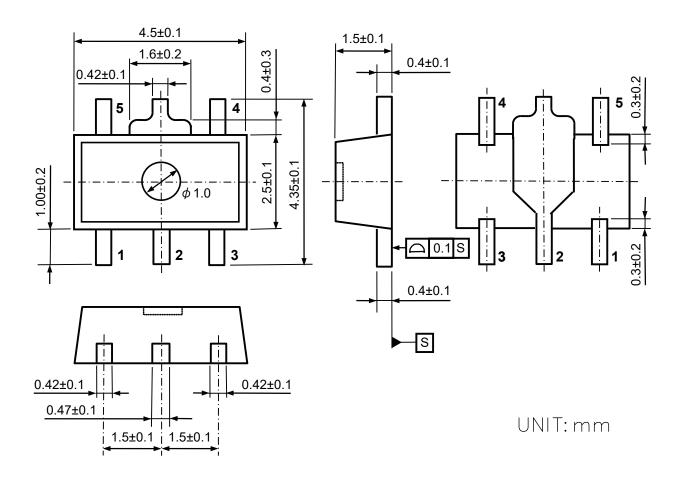
I



DFN(PLP)1820-6 Package Dimensions (Unit: mm)

i

<sup>\*</sup> The tab on the bottom of the package is substrate level (GND). It is recommended that the tab be connected to the ground plane on the board, or otherwise be left floating.



**SOT-89-5 Package Dimensions** 

\/er ∆

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions
Environment	Mounting on Board (Wind Velocity = 0 m/s)
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)
<b>Board Dimensions</b>	76.2 mm × 114.3 mm × 0.8 mm
	Outer Layer (First Layer): Less than 95% of 50 mm Square
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square
Through-holes	φ 0.3 mm × 13 pcs

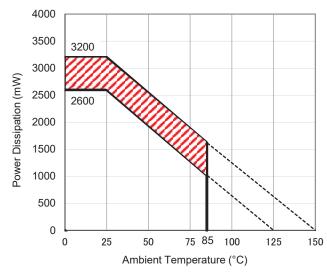
#### **Measurement Result**

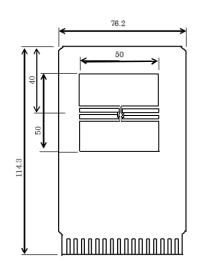
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result
Power Dissipation	2600 mW
Thermal Resistance (θja)	θja = 38°C/W
Thermal Characterization Parameter (ψjt)	ψjt = 13°C/W

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)
13,000 hours	9 years

i

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

Item	Measurement Conditions		
Environment	Mounting on Board (Wind Velocity = 0 m/s)		
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)		
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm		
	Outer Layer (First Layer): Less than 95% of 50 mm Square		
Copper Ratio	Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square		
	Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square		
Through-holes	φ 0.3 mm × 28 pcs		

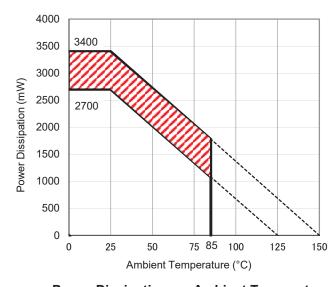
#### **Measurement Result**

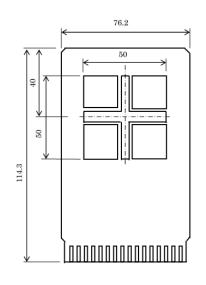
 $(Ta = 25^{\circ}C, Tjmax = 125^{\circ}C)$ 

Item	Measurement Result		
Power Dissipation	2700 mW		
Thermal Resistance (θja)	θja = 37°C/W		
Thermal Characterization Parameter (ψjt)	ψjt = 7°C/W		

θja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





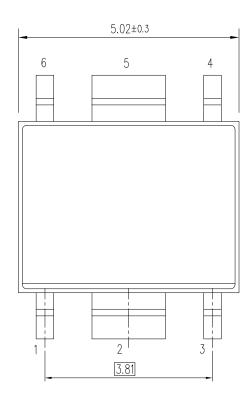
Power Dissipation vs. Ambient Temperature

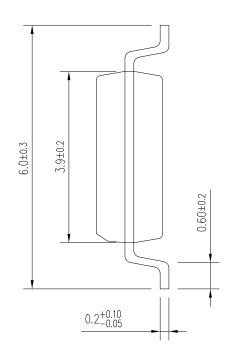
**Measurement Board Pattern** 

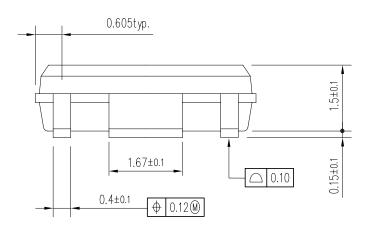
The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)		
13,000 hours	9 years		

i







UNIT: mm

**HSOP-6J Package Dimensions** 

The power dissipation of the package is dependent on PCB material, layout, and environmental conditions. The following measurement conditions are based on JEDEC STD. 51-7.

#### **Measurement Conditions**

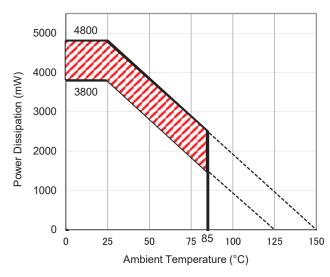
Item	Measurement Conditions		
Environment	Mounting on Board (Wind Velocity = 0 m/s)		
Board Material	Glass Cloth Epoxy Plastic (Four-Layer Board)		
Board Dimensions	76.2 mm × 114.3 mm × 0.8 mm		
Copper Ratio	Outer Layer (First Layer): Less than 95% of 50 mm Square Inner Layers (Second and Third Layers): Approx. 100% of 50 mm Square Outer Layer (Fourth Layer): Approx. 100% of 50 mm Square		
Through-holes	φ 0.3 mm × 21 pcs		

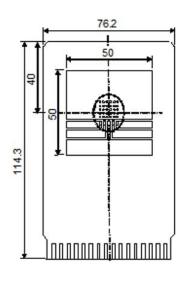
Measurement ResultItemMeasurement ResultPower Dissipation3800 mWThermal Resistance ( $\theta$ ja) $\theta$ ja = 26°C/W

Thermal Characterization Parameter (ψjt) ψjt = 7°C/W

 $\theta$ ja: Junction-to-Ambient Thermal Resistance

ψjt: Junction-to-Top Thermal Characterization Parameter





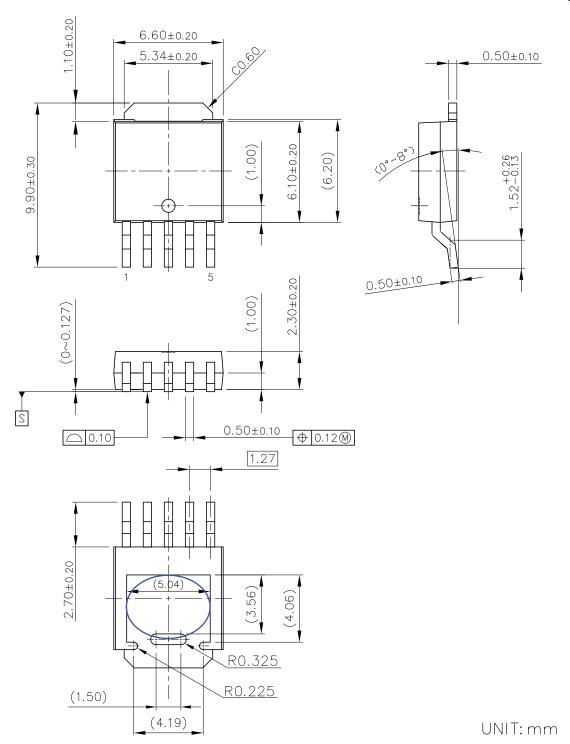
Power Dissipation vs. Ambient Temperature

**Measurement Board Pattern** 

The above graph shows the power dissipation of the package at Tjmax = 125°C and Tjmax = 150°C. Operating the device in the hatched range might have a negative influence on its lifetime. The total hours of use and the total years of use must be limited as follows:

Total Hours of Use	Total Years of Use (4 hours/day)		
13,000 hours	9 years		

I



**TO-252-5-P2 Package Dimensions** 

I

<sup>\*</sup> The tab on the bottom of the package shown by blue circle is a substrate potential (GND). It is recommended that this tab be connected to the ground plane on the board but it is possible to leave the tab floating.



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